

E151 Lecture 8

Amplifier Design and Voltage Swing

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Disclaimer

These are notes for Prof. Spencer to give the lecture, they were not intended as a reference for students. Students asked for them anyway, so I'm putting them up as a courtesy. Remember that they are not intended as a substitute for attending lecture.

Built an Amplifier, Biasing Improvements

- Get to a_v , r_{in} and r_{out} indirectly
- Invoke voltage swing with final example
- We have been building up a sense of design specs for amps

$I_C = \beta I_B (e^{V_{be}/kT} - 1)$
 $V_{ce} = 0 - g_m V_i (r_o || R)$
negation is phase shift $\uparrow V_i$ asks $\downarrow V_o$
 $I_{CQ} = \frac{V_{BB} - V_{BE,ON}}{R_B}$
 $V_o = -g_m (r_o || R) \cdot \frac{R_B || r_{\pi}}{R_B + R_B || r_{\pi}}$
see input loading, care about R_{in}
 What if $I_C \cdot R_E > V_B$ in FAR?
Not just a divider! $I_C = \frac{V_B - V_{BE,ON}}{R_E}$
 Bypass ground collector \rightarrow get same gain, changes?

Design Specifications for Amplifiers

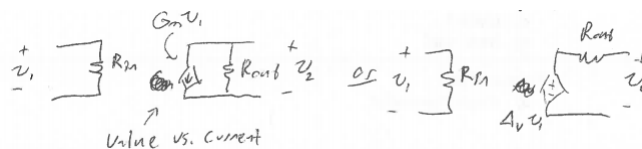
- Suggests a generalized 2 port model for amplifiers ... no Z12, so easy

Sometimes care about a_i
 $d_{io}/d_{ii} |$ out short = beta

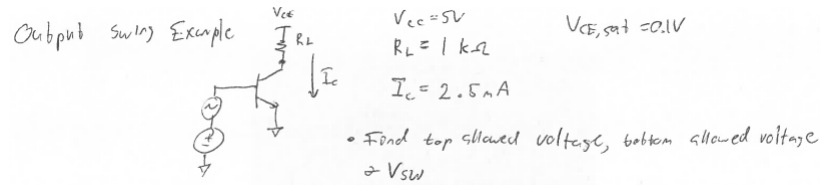
Symbol	Name	Calc
a_v	Voltage gain	$d_{vo}/d_{vi} $ out open
r_{in}	Input resistance	$d_{ii}/d_{vi} $ out short
r_{out}	Output resistance	$d_{io}/d_{vo} $ in short
V_{SW}	Voltage swing	$V_{O_MAX} - V_{O_MIN}$
I_{IN}	Input bias current	Large signal I_{IN}
f_{low}	Low f -3dB corner	Measure for now

Fall straight out of small signal,
Must measure with power on!
 (small sig. open/short, not big)

Must find nominal V_O and
 figure out allowed excursions
 $2 * \min(V_{O_MAX} - V_O, V_{O_MIN} - V_O)$

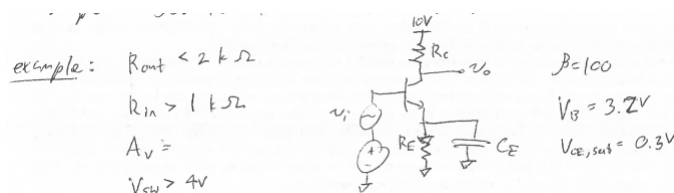


Output Swing Example



1. Find $V_O = V_{CC} - I_C \cdot R_L$
 2. If V_O down, when do we leave FAR? $V_{MIN} = V_{CE,SAT}$
 3. If V_O up, when do we leave FAR? $V_{MAX} = V_{CC}$ (cutoff)
 4. Check at input: $A_v = g_m \cdot R_L = 100$, so $+2.5V$ $V_O/2$ is $\sim 25mV$ @in
- Approximate: get distortion before sat/cutoff \rightarrow use FFT & 1-2V margin

Design Process: Specs to I_C / R values



- Start w/ easy constraints:

• Eg: $r_{\pi} = \frac{\beta}{g_m} = \frac{\beta V_T}{I_C} = \frac{100 \cdot 25mV}{I_C} > 1k\Omega \rightarrow I_C > 2.5mA$

min power by setting $I_C = 2.5mA$
 $\approx 100mA$

- Unusual, easy constraints are usually at output: V_{SW} or rout constraints

- Propagate

• know $V_E = 2.8V$, so need $R_E = 1k$

- $V_{OMAX} = 10V$, $V_{OMIN} = V_E + V_{CE,SAT} = 2.8V$, $\frac{1}{2}$ way max swing $\rightarrow V_O = 6.4V$

$R_C = 1.6k$